TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# **TC7S86F, TC7S86FU**

# **EXCLUSIVE OR GATE**

The TC7S86 is a high speed C<sup>2</sup>MOS EXCLUSIVE OR GATE fabricated with silicon gate C<sup>2</sup>MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the C<sup>2</sup>MOS low power dissipation.

Input and output buffers are provided which offer high noise immunity and stable output. All inputs are equipped with protection circuits against static dischage or transient excess voltage.

Output current are 1/2 compared to TC74HC series models.

#### FEATURES

- High Speed .....  $t_{pd} = 10ns$  (Typ.) at  $V_{CC} = 5V$
- Low Power Dissipation ...... I<sub>CC</sub> = 1µA (Max.) at Ta = 25°C
- High Noise Immunity .....  $V_{NIH} = V_{NIL}$ = 28% V<sub>CC</sub> (Min.)
- Output Drive Capability ..... 5 LSTTL Loads
- Symmetrical Output Impedance ...  $|I_{OH}| = I_{OL}$ = 2mA (Min.)
- Balanced Propagation Delays  $\dots$   $t_{pLH} = t_{pHL}$
- Wide Operating Voltage Range ... V<sub>CC (opr)</sub> = 2~6V



Weight SSOP5-P-0.95 : 0.016g (Typ.) SSOP5-P-0.65A : 0.006g (Typ.)

#### MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	Vcc	-0.5~7	V
DC Input Voltage	VIN	-0.5~V <sub>CC</sub> +0.5	V
DC Output Voltage	Vout	-0.5~V <sub>CC</sub> +0.5	V
Input Diode Current	Iк	± 20	mA
Output Diode Current	ІОК	± 20	mA
DC Output Current	<sup>I</sup> OUT	± 12.5	mA
DC V <sub>CC</sub> /Ground Current	lcc	± 25	mA
Power Dissipation	PD	200	mW
Storage Temperature	T <sub>stg</sub>	- 65~150	°C
Lead Temperature (10s)	Т	260	°C

#### TRUTH TABLE

А	В	Y
Н	Н	L
L	Н	Н
Н	L	Н
L	L	L

## LOGIC DIAGRAM







# PIN ASSIGNMENT (TOP VIEW)





# **RECOMMENDED OPERATING CONDITIONS**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2~6	V
Input Voltage	VIN	0~V <sub>CC</sub>	V
Output Voltage	VOUT	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	- 40~85	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	0~1000 (V <sub>CC</sub> = 2.0V) 0~ 500 (V <sub>CC</sub> = 4.5V) 0~ 400 (V <sub>CC</sub> = 6.0V)	ns

# **DC ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC SYMBOL		TEST CONDITION			Т	a = 25°	°C	Ta = -4	UNIT	
CHARACTERISTIC			CONDITION	Vcc	MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level				2.0	1.5	_	—	1.5	—	
Input Voltage	VIH		—	4.5	3.15	—	-	3.15	—	V
,				6.0	4.2		<u> </u>	4.2	—	
Low-Level				2.0	-		0.5	—	0.5	
Input Voltage			_	4.5	-		1.35	—	1.35	V
				6.0			1.8	—	1.8	
	Voн	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2.0	1.9	2.0	—	1.9	—	
High-Level			l <sub>OH</sub> = −20μA	4.5	4.4	4.5	—	4.4	—	
Output Voltage				6.0	5.9	6.0		5.9	—	V
Output Voltage			l <sub>OH</sub> = – 2mA	4.5	4.18	4.31	—	4.13	—	
			l <sub>OH</sub> = – 2.6mA	6.0	5.68	5.80	—	5.63	—	
		or VIL		2.0	_	0.0	0.1	—	0.1	
			l <sub>OL</sub> = 20μA	4.5		0.0	0.1	—	0.1	
Low-Level	V <sub>OL</sub>			6.0		0.0	0.1	—	0.1	V
Output Voltage			I <sub>OL</sub> = 2mA	4.5	_	0.17	0.26	—	0.33	
			$I_{OL} = 2.6 mA$	6.0		0.18	0.26	—	0.33	
Input Leakage Current	IIN	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	_	_	±0.1	_	± 1.0	μΑ
Quiescent Supply Current	lcc	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	_	_	1.0	_	10.0	μΑ

Output currents are 1/2 compared to TC74HC series models.

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C			
CHARACTERISTIC	STIVIBOL			TYP.	MAX.	UNIT	
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>	_	_	4	8		
Propagation Delay	t <sub>pLH</sub>			10	17	ns	
Time	t <sub>pHL</sub>						

## AC ELECTRICAL CHARACTERISTICS ( $C_L = 15pF$ , $V_{CC} = 5V$ , $Ta = 25^{\circ}C$ , Input $t_r = t_f = 6ns$ )

# AC ELECTRICAL CHARACTERISTICS ( $C_L = 50pF$ , Input $t_r = t_f = 6ns$ )

CHARACTERISTIC SYMBOL		TEST CONDITION	Ta = 25°C			Ta = - 4			
	TEST CONDITION		MIN.	TYP.	MAX.	MIN.	MAX.		
Output Transition	<b>+</b>		2.0	—	50	125	—	155	
	tTLH	—	4.5	_	14	25	_	31	
Time t <sub>THL</sub>		6.0	—	12	21	—	26		
Proposition Dolou	+		2.0	_	48	100	—	125	ns
Propagation Delay Time	t <sub>pLH</sub>	—	4.5		12	20	_	25	
Time t <sub>pHL</sub>	<sup>ч</sup> рНL		6.0		9	17	_	21	
Input Capacitance	CIN	_		—	5	10	_	10	рF
Power Dissipation Capacitance	C <sub>PD</sub>	(Note 1)		_	18	_	_	_	pF

Note 1 : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $|CC(opr)| = CPD \cdot VCC \cdot fIN + |CC|$ 

# PACKAGE DIMENSIONS

SSOP5-P-0.95







Weight : 0.016g (Typ.)

PACKAGE DIMENSIONS SSOP5-P-0.65A





Weight : 0.006g (Typ.)

Unit : mm

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